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Update on IHEP RD50 activities

Wednesday 12 June 2019 13:20 (20 minutes)

The first LGAD sensors designed and fabricated in China have been evaluated including the basic electrical properties as well as timing properties. The status of the planned proton irradiation in China will also be presented. In addition, the joint project to produce Schottky diodes on epitaxial silicon for radiation damage study will be introduced.

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Session Classification: Precision Timing Detectors